

CBCS SCHEME

USN

--	--	--	--	--	--	--	--	--	--

15NT73

Seventh Semester B.E. Degree Examination, July/August 2021

MEMS and NEMS

Time: 3 hrs.

Max. Marks: 80

Note: Answer any FIVE full questions.

- 1 a. Enumerate the concept of miniaturization and list the benefits. (08 Marks)
b. Discuss the various steps involved in fabrication of IC's. (08 Marks)
- 2 a. Write a note on micro-sensors and micro actuators. (08 Marks)
b. Explain briefly about MEMS packages. (08 Marks)
- 3 a. Define transducer and explain the working of
i) Capacitive transducer ii) Optical waveguide transducer. (09 Marks)
b. Explain the working of schottky diode based transducer (07 Marks)
- 4 a. Briefly about :
i) Quartz crystal imbalance ii) Film bulk acoustic wave resonator. (10 Marks)
b. Explain importance of cantilever based transducer. (06 Marks)
- 5 a. With a sketch, explain surface and Bulk micro machining. (10 Marks)
b. List and explain various etching methods. (06 Marks)
- 6 a. With a sketch, explain the concept of photolithography. (10 Marks)
b. Define piezoelectric effect, and explain the various mechanisms involved in it. (06 Marks)
- 7 a. Explain the concept of Reliability and stability. (06 Marks)
b. Discuss briefly about the various MEMS failure mechanism. (10 Marks)
- 8 a. Enumerate the concept of CMOS and transmitters. (06 Marks)
b. Write a note on : i) Traceability ii) Calibration. (06 Marks)
c. Discus the working of signal amplifier. (04 Marks)
- 9 a. Define NEMS, Explain Nano machining of NEMS. (06 Marks)
b. List and explain the steps involved in fabrication of NEMS. (10 Marks)
- 10 a. Write a short note on : i) Stencil lithography ii) Sacrificial etching (08 Marks)
b. Explain briefly about future challenges and applications of NEMS. (08 Marks)

Important Note : 1. On completing your answers, compulsorily draw diagonal cross lines on the remaining blank pages.
2. Any revealing of identification, appeal to evaluator and /or equations written eg. 42+8 = 50, will be treated as malpractice.